

ACTS74MS

Radiation Hardened Dual D Flip Flop with Set and Reset

January 1996

Features

- Devices QML Qualified in Accordance with MIL-PRFF-38535
- Detailed Electrical and Screening Requirements are Contained in SMD# 5962-96713 and Intersil's QM Plan
- 1.25 Micron Radiation Hardened SOS CMOS
- Single Event Upset (SEU) Immunity: <1 x 10⁻¹⁰ Errors/Bit/Day (Typ)

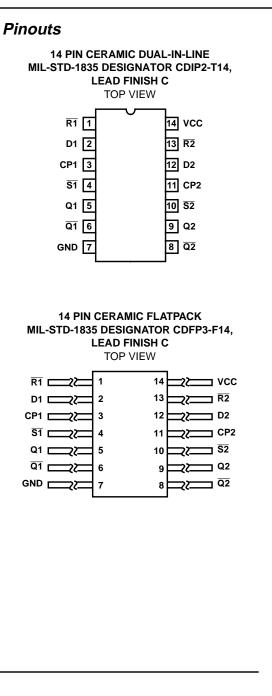
- Latch-Up Free Under Any Conditions
- Military Temperature Range-55°C to +125°C
- Significant Power Reduction Compared to ALSTTL Logic
- DC Operating Voltage Range 4.5V to 5.5V
- Input Logic Levels
 - VIL = 0.8V Max
 - VIH = VCC/2 Min
- Input Current \leq 1µA at VOL, VOH
- Fast Propagation Delay 20ns (Max), 13ns (Typ)

Description

The Intersil ACTS74MS is a Radiation Hardened Dual D Flip Flop with Set(s) and Reset (R). The logic level at data input is transferred to the output during the positive transition of the clock. The Set and Reset are independent from the clock and accomplished by a low level on the appropriate input.

The ACTS74MS utilizes advanced CMOS/SOS technology to achieve high-speed operation. This device is a member of a radiation hardened, high-speed, CMOS/SOS Logic Family.

The ACTS74MS is supplied in a 14 lead Ceramic Flatpack (K suffix) or a 14 Lead Ceramic Dual-In-Line Package (D suffix).

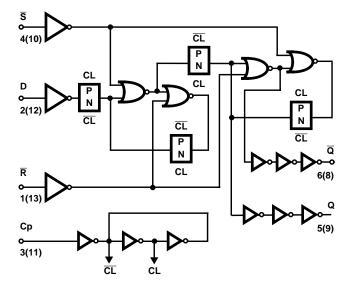


Ordering Information

PART NUMBER	TEMPERATURE RANGE	SCREENING LEVEL	PACKAGE
5962F9671301VCC	-55°C to +125°C	MIL-PRF-38535 Class V	14 Lead SBDIP
5962F9671301VXC	-55°C to +125°C	MIL-PRF-38535 Class V	14 Lead Ceramic Flatpack
ACTS74D/Sample	25°C	Sample	14 Lead SBDIP
ACTS74K/Sample	25°C	Sample	14 Lead Ceramic Flatpack
ACTS74HMSR	25°C	Die	Die

CAUTION: These devices are sensitive to electrostatic discharge; follow proper IC Handling Procedures. http://www.intersil.com or 407-727-9207 | Copyright © Intersil Corporation 1999

Functional Diagram



TRUTH TABLE

	INP	OUTPUTS			
SET	RESET	СР	D	Q	Q
L	Н	Х	Х	Н	L
н	L	Х	Х	L	Н
L	L	Х	Х	H (Note 2)	H (Note 2)
н	Н		н	Н	L
н	Н		L	L	Н
н	Н	L	Х	Q0	$\overline{Q0}$
-	evel (Steady vel (Steady	,	X = Don't Care = Transition from Low to High Level		

NOTES:

- 1. Q0 = the level of Q before the indicated input conditions were established.
- 2. This configuration is nonstable, that is, it will not persist when set and reset inputs return to their inactive (high) level.

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Die Characteristics

DIE DIMENSIONS:

88 mils x 88 mils 2240mm x 2240mm

METALLIZATION:

Type: AlSi Metal 1 Thickness: 7.125kÅ ±1.125kÅ Metal 2 Thickness: 9kÅ ±1kÅ

GLASSIVATION:

Type: SiO₂ Thickness: 8kÅ ±1kÅ

WORST CASE CURRENT DENSITY: <2.0 x 10⁵A/cm²

BOND PAD SIZE:

110μm x 110μm 4.3 mils x 4.3 mils

Metallization Mask Layout

